



1N4001 THRU 1N4007

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

GENERAL PURPOSE SILICON RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Idea for printed circuit board
- ◆ Open Junction chip
- ◆ Low reverse leakage
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed 250 °C/10 seconds at terminals

Mechanical Data

Case : JEDEC DO-41 Molded plastic body

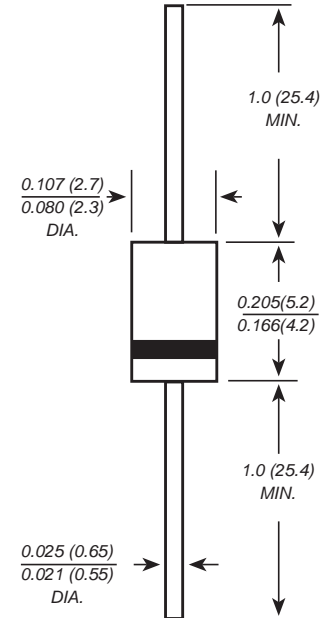
Terminals : Solder plated, solderable per MIL-STD-750, Method 2026

Polarity : Polarity symbol marking on body

Mounting Position : Any

Weight : 0.012 ounce, 0.33 grams

DO-41



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

| Parameter | SYMBOLS | 1N4001 | 1N4002 | 1N4003 | 1N4004 | 1N4005 | 1N4006 | 1N4007 | UNITS |
|---|-----------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------------------|
| | | MDD 1N4001 | MDD 1N4001 | MDD 1N4001 | MDD 1N4001 | MDD 1N4001 | MDD 1N4001 | MDD 1N4001 | |
| Maximum repetitive peak reverse voltage | V_{RMM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum average forward rectified current at $T_L=110^\circ\text{C}$ | $I_{(AV)}$ | 1.0 | | | | | | | A |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 30 | | | | | | | A |
| Maximum instantaneous forward voltage at 1.0A | V_F | 1.10 | | | | | | | V |
| Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$ $T_A=100^\circ\text{C}$ | I_R | 5.0 50.0 | | | | | | | μA |
| Typical junction capacitance (NOTE 1) | C_J | 15.0 | | | | | | | pF |
| Typical thermal resistance (NOTE 2) | $R_{\theta JA}$ | 65.0 | | | | | | | $^\circ\text{C}/\text{W}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -55 to +150 | | | | | | | $^\circ\text{C}$ |

- Note:**
1. Measured at 1.0MHz and applied reverse voltage of 4.0V D.C.
 2. Mounted on 10cm x 10cm x 1mm copper pad area
 3. The typical data above is for reference only.



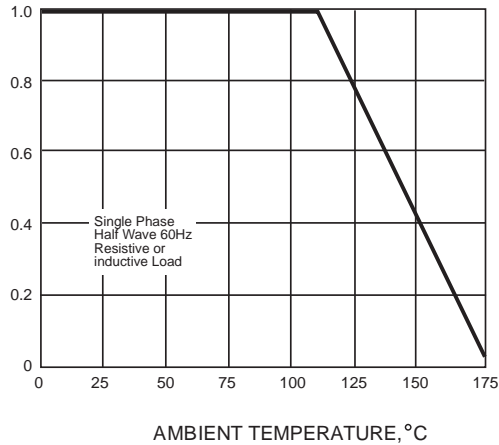
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Ratings And Characteristic Curves

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

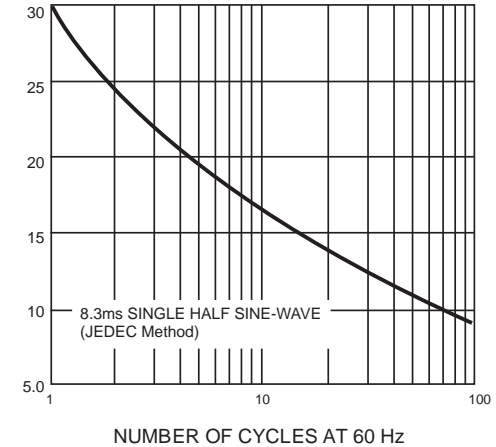
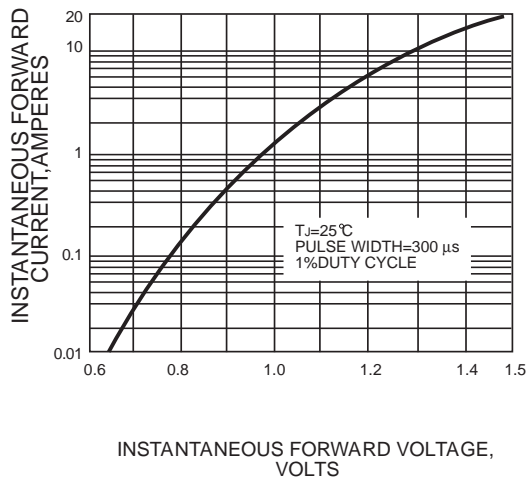


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

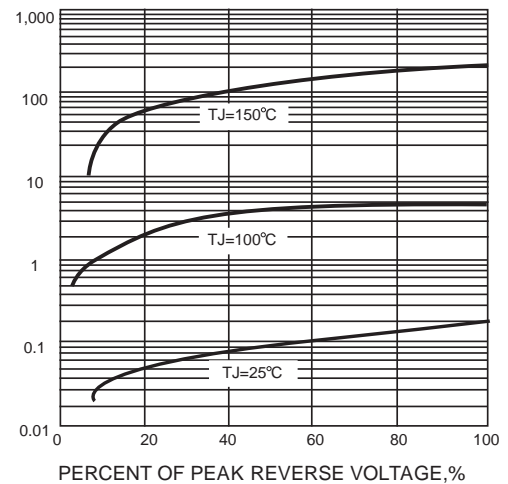
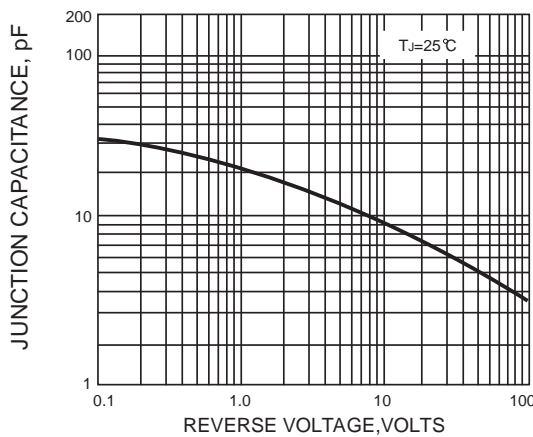
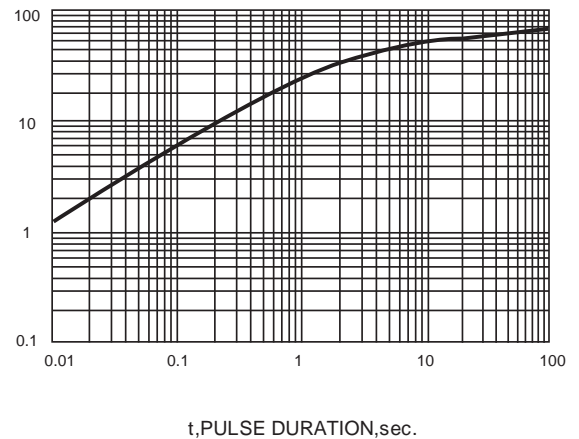


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The curve above is for reference only.

单击下面可查看定价，库存，交付和生命周期等信息

[>>MDD\(辰达行\)](#)